

# Lecture 21 – Nanostructures (semiconductor)

**Lecture 21: Nanostructures**  
**Kittel Ch 18**  
 + extra material in the class notes

Physics 460 F 2006 Lect 24 1

**Outline**

- Electron in a box (again)
- Examples of nanostructures
- Created by Applied Voltages  
 Patterned metal gates on semiconductors  
 Create “dots” that confine electrons
- Created by material structures  
 Clusters of atoms, e.g.,  $\text{Si}_{29}\text{H}_{36}$ , CdSe clusters  
 Clusters of atoms embedded in an insulator  
 e.g., Si clusters in  $\text{SiO}_2$   
 Buckyballs, nanotubes, . . .
- How does one study nanosystems?
- What are novel properties?
- See Kittel Ch 18 and added material in the lecture notes

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**Probes to determine structures**

- Transmission electron microscope (TEM)
- Scanning electron microscope (SEM)
- Scanning tunneling microscope (STM) – more later

Figures in Kittel Ch 18

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**How small – How large?**

- “Nano” means size ~ nm
- Is this the relevant scale for “nano effects” ?
  - Important changes in chemistry, mechanical properties
  - Electronic and optical properties
  - Magnetism (later)
  - Superconductivity (later)
- Changes in chemistry, mechanical properties
  - Expect large changes if a large fraction of the atoms are on the surface
- Electronic and optical properties
  - Changes due to the importance of surface atoms
  - Quantum “size effects” – can be very large and significant \

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**“Surface” vs “Bulk” in Nanosystems**

- Consider atomic “clusters” with ~ 1 nm
- Between molecules (well-defined numbers and types of atoms – well-defined structures) and condensed matter (“bulk” properties are characteristic of the “bulk” independent of the size – surface effects separate)
- Expect large changes if a large fraction of the atoms are on the surface
- Typical atomic size ~ 0.3 nm
- Consider a sphere – volume  $4\pi R^3/3$ , surface area  $4\pi R^2$  --- Rough estimates
  - $R = 3 \text{ nm} \Rightarrow \sim 10^3$  atoms -  $10^2$  on the surface – 10%
  - $R = 1.2 \text{ nm} \Rightarrow \sim 64$  atoms - 16 on the surface – 25%
  - $R = 0.9 \text{ nm} \Rightarrow \sim 27$  atoms - 9 on the surface – 33%

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**Quantum Size Effects**

- We can make estimates using the “electron in a box” model of the previous lecture
- The key quantity that determines the quantum effects is the mass
- When can we use  $m = m_{\text{electron}}$  ?  
 In typical materials (metals like Na, Cu, .. the intrinsic electrons in semiconductors,...
- When do we use the effective mass  $m^*$   
 For the added electrons or holes in a semiconductor

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## Quantization for electrons in a box in one dimension

- $E_n = (\hbar^2/2m) k_z^2$ ,  $k_z = n\pi/L$ ,  $n = 1, 2, \dots$   
 $= (\hbar^2/4mL^2) n^2$ ,  $n = 1, 2, \dots$   $m = m_e$   
or  $m = m^*$
- Lowest energy solutions with  $\Psi_n(x) = 0$  at  $x = 0, L$

Here we emphasize the case where the box is very small

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## Electron in a box

- If the electrons are confined in a cubic box of size L in all three dimensions then the total energy for the electrons:

$$E(n_x, n_y, n_z) = (\hbar^2/4m L^2) (n_x^2 + n_y^2 + n_z^2)$$

The wavefunction has this form in each direction

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## Nanoscale clusters

- Estimate the quantum size effects using the electron in a box model
- The discrete energies for electrons are given by  
 $E = (\hbar^2/4m L^2) (n_x^2 + n_y^2 + n_z^2)$
- The typical energy scale is  
 $\hbar^2/(4m L^2) = 3.7 \text{ eV}/L^2$   
 where L is in nm
- Thus for 3 nm, the confinement energy is  
 $\sim 3 \times 3.7 \text{ eV}/9 \sim 1 \text{ eV}$   
 As large as the gap in Si!

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## Nanoscale clusters - II

- Example: Silicon clusters
  - Must have other atoms to "passivate" the "dangling bonds" at the surface – is ideal
  - $\text{Si}_{29}\text{H}_{36}$  – bulk-like cluster with 18 surface atoms, each with 2 H attached
  - $\text{Si}_{28}\text{H}_{24}$  – 5 bulk-like atoms at the center and 24 rebonded surface atoms, each with one H attached – shown in the figure
- Carbon "Buckyballs"
  - Sheet of graphite (graphene) rolled into a ball ( $\text{C}_{60}$  forms a soccer ball with diameter ~ 1nm)
  - Graphene is a zero gap material, and the size effect causes  $\text{C}_{60}$  to have a gap of ~ 2eV

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## Special Presentation Prof. Munir Nayfeh

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## Semiconductor Quantum Dots

- Structures with electrons (holes) confined in all three directions
- The discrete energies for electrons are given by  
 $E = (\hbar^2/2m L^2) (n_x^2 + n_y^2 + n_z^2)$
- The energy scale factor is  
 $\hbar^2/(2m L^2) = 3.7 \text{ eV}/(m_0/m^* L^2)$   
 where L is in nm
- If  $m^* = 0.01 m_0$ , then the confinement energy is  
 $\sim 1 \text{ eV}$  for  $L \sim 30 \text{ nm}$   
 $\sim 0.04 \text{ eV}$  for  $L \sim 150 \text{ nm}$   
 (note  $300\text{K} \sim .025 \text{ eV}$ )

Semi-conductor Small-gap e.g. GaAs      Semi-conductor Large-gap e.g. AlAs

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## Semiconductor Structures

600 nm

1000 nm

1 μm

90 Å, 120 Å, 75 Å

GATE

n+GaAs, AlGaAs, InGaAs, GaAs Spacer, Schottky Barrier, Ohmic contact

Tuning Gates, Back Gate

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## One dimensional nanowires

- The motion of the electrons is **exactly like the "electron in a box"** problems discussed in Kittel, ch. 6
- Except the electrons have an effective mass  $m^*$**
- And in this case, the box has length  $L$  in two directions (the  $y$  and  $z$  directions) and large in the  $x$  direction ( $L_x$  very large)

- Key Point: For ALL "electron in a box" problems, the energy is given by

$$E(\mathbf{k}) = (\hbar^2/2m) (k_x^2 + k_y^2 + k_z^2)$$

For this case  $m = m^*$  and  $k_y = (\pi/L) n_y, k_z = (\pi/L) n_z$

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## Quantized one-dimensional bands

- $E_n(k_x, k_y) = (\hbar^2/2m^*)(\pi/L)^2 (n_y^2 + n_z^2) + (\hbar^2/2m^*) k_x^2$   
 $n = 1, 2, \dots$

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## Density of States in two-dimensions

- Density of states (DOS) for each band is constant
- Example - electrons fill bands in order

- The density of states in a nanotube have this form – See Kittel, Ch 18

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## Quantized one-dimensional bands

- What does this mean? One can make one-dimensional electron gas in a semiconductor!
- Example - electrons fill bands in order

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## Nanotubes

- Carbon nanotubes are similar except there is a special "zero gap" feature in some cases
- Electrons can be added using a FET

More description in Kittel Ch 18

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# Lecture 21 – Nanostructures (semiconductor)

## Summary

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## Next time

- Metals – start superconductivity

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